

Poster Session P2, Tuesday, October 1, 15:30-18:00

P2-1	The role of oxygen octahedra connectivity in orthorhombic perovskite heterostructures Thibault, Clémentine (University of Geneva)
P2-2	Interfacial charge-transfer in 3d/5d oxide heterostructures Fuchs, Dirk (Karlsruhe Institute of Technology)
P2-3	Tuning the interlayer coupling in $\text{La}_{0.7}\text{Sr}_{0.3}\text{Mn}_{0.95}\text{Ru}_{0.05}\text{O}_3 / \text{LaNiO}_3$ multilayers with perpendicular magnetic anisotropy Schöpf, Jörg (University of Cologne)
P2-4	Growth control of magnetic perovskite/2D topological insulator heterostructures - towards tailoring interfacial magnetic interactions Brzozowski, Damian (Norwegian University of Science and Technology)
P2-5	Superlattice domain engineering by pulsed laser deposition Hallsteinsen, Ingrid (Norwegian University of Science and Technology)
P2-6	Oscillatory conduction behavior in an all-epitaxial $(\text{La}_{2/3}, \text{Sr}_{1/3})\text{MnO}_3 / \text{SrTiO}_3 / \text{Nb:SrTiO}_3$ tunneling heterostructure Endo, Tatsuro (University of Tokyo)
P2-7	Engineering the magnetic transition temperatures and the rare earth exchange interaction in oxide heterostructures Moreno-López, Juan Carlos (TU Wien)
P2-8	Large spin-valve effect in a $\text{La}_{0.67}\text{Sr}_{0.33}\text{MnO}_3$ -based spin-MOSFET with two easy-magnetization axes induced by inserting a LaMnO_3 buffer layer Nakamura, Aoi (University of Tokyo)
P2-9	Operando transmission soft x-ray absorption spectroscopy of Li-ion battery structure by x-ray excited optical luminescence Kitamura, Miho (NanoTerasu Center QST, Japan)
P2-10	Custom-shaped freestanding conducting oxide membranes on demand D'Alessio, Andrea (Technical University of Denmark)
P2-11	Step-edge-induced structure modulation in freestanding BaTiO_3 membranes Yun, Shinhee (Technical University of Denmark)
P2-12	Can we control the release dynamics of freestanding oxide membranes? Høgfeldt Christoffersen, Christina (Technical University of Denmark)
P2-13	Thickness controlled spalling for oxide freestanding films via graphene buffer layers Nayak, Kapil (Forschungszentrum Juelich)
P2-14	Resonant photoemission spectroscopy investigation of the ferromagnetism enhancement in a $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$ membrane free from a SrTiO_3 substrate Takeda, Takahito (Hiroshima University)

P2-15	Bulk micro-machining of SrTiO ₃ substrates for device applications Manca, Nicola (CNR-SPIN, Genova)
P2-16	Phase transitions in freestanding (K,Na)NbO ₃ thin films grown by Metal-Organic Vapor Phase Epitaxy Maltitz, Jeremy (Leibniz Institut für Kristallzüchtung, Berlin)
P2-17	Wrinkle-driven symmetry evolution in PbTiO ₃ /SrRuO ₃ freestanding membrane Roh, Changjae (University of Geneva)
P2-18	First order polarization process and anisotropic in-plane ferroelectricity in CaTiO ₃ thin films Korosec, Lukas (University of Geneva)
P2-19	Investigating 3D domain structures and superdomains in ferroelectric PbTiO ₃ based heterostructures on DyScO ₃ Tovaglieri, Ludovica (University of Geneva)
P2-20	Strain engineering and ferroelectric/antiferroelectric properties of epitaxial perovskite oxide NaNbO ₃ thin films Shengwei, Zeng (Institute of Materials Research and Engineering, Singapore)
P2-21	Zirconium oxide ferroelectrics for memory devices Li, Yulei (University of Groningen)
P2-22	Controllable periodic domains in BaTiO ₃ thin films Wu, Liyan (Drexel University)
P2-23	Strain, Young's modulus, and structural transition of EuTiO ₃ thin films probed by micro-mechanical methods Marré, Daniele (CNR-SPIN, Genova)
P2-24	Oxygen-driven phenomena in ferroelectric Hf(Zr)O ₂ and AlScN thin films – A HAXPES study Rehm, Oliver (Universität Konstanz)
P2-25	Optimizing HfO ₂ based trilayer memristor with ZrO _{2-x} oxygen vacancy reservoirs for advanced neuromorphic computing Boynazarov, Turgun (Sejong University)
P2-26	Interface engineering in IGZO-based devices Yuan, Peijia (Forschungszentrum Jülich)
P2-27	Area-type resistive switching Pr _{0.7} Ca _{0.3} MnO ₃ /WO _x devices Moos, Zoe (Forschungszentrum Jülich)
P2-28	Electrochemical impedance spectroscopy of artificial protonic synaptic devices Besisa, Nada H.A. (Kyushu University)
P2-29	Review of the proposed switching mechanisms in Pr _{1-x} Ca _x MnO ₃ heterostructures considering the recent process with amorphous PCMO Buczek, Max (Forschungszentrum Jülich)
P2-30	Remotely triggered resistive switching in multiterminal VO ₂ devices Smink, Sander (University of Twente)

P2-31	High temperature cluster spin glass behavior in defect controlled $\text{Y}_3\text{Fe}_5\text{O}_{12}$ thin films towards neuromorphic computation Sarker, Md Shamim (University of Tokyo)
P2-32	Non-volatile electro-thermal memristive behaviour in planar NdNiO_3 thin films Tahouni-Bonab, Farnaz (Universität Tübingen)
P2-33	All HfO_x resistive switches with artificial virtual electrode and self-limited oxide layer Schreyer, Philipp (TU Darmstadt)
P2-34	Growth conditions and characterization of $\text{SrCoO}_{3-\delta}$ thin film protonic conductor for electrochemical resistive switching Shih, Li-Chung (TU Darmstadt)
P2-35	Stable conductance modulation in WO_3 -based proton devices via O_2 removal Tsuji, Masaki (Kyushu University)
P2-36	Influence of hafnium oxide layer thickness on the performance of $\text{Cu}/\text{HfO}_2/\text{Pt}$ CBRAM device Kim, Taewook (TU Darmstadt)
P2-37	Electric-field control of the local thermal conductivity in negative charge transfer oxides Rivadulla, Francisco (Universidade de Santiago de Compostela)
P2-38	Nano engineered solid state ionic metal oxides for near-room temperature oxygen conductivity Dhanalakshmi, R. Baby (Denmark Technical University)
P2-39	Resonant $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$ suspended microbridges: mechanical characterisation, integration of the piezoelectric layer and application as bolometers Tarsi, Gaia (Normandie University)
P2-40	Electrically tunable free space barium strontium titanate (BST) optical filters Vakili, Mojdeh (TU Darmstadt)
P2-41	Freestanding SrMoO_3 membrane single layers and complete devices: strain mechanisms and high-performance varactors Ruan, Yating (TU Darmstadt)
P2-42	All-oxide thin-film varactors with SrMoO_3 bottom electrodes and Mn/Ni-doped BST for sub-6 GHz applications Komissinskiy, Philipp (TU Darmstadt)
P2-43	$(\text{La}_{0.7}\text{Sr}_{0.3})\text{MnO}_3$ trampoline resonators for magnetometers and IR bolometers Pellegrino, Luca (SPIN Institute, Genoa)
P2-44	Nanomechanical probing of the elasto-plastic responses of thin film SrTiO_3 Fang, Xufei (Karlsruhe Institute of Technology)
P2-45	Epitaxial NiFe_2O_4 films model systems for studying the inverse spinel facet OER activity Ratovskii, Vadim (University of Twente)

P2-46	Drug delivery efficiency of polymer-modified iron oxide nanoparticles loaded with chrysin Karimova, Aynura (Baku State University)
P2-47	Effect of the concentration and thermal annealing temperature to the physical properties of GO/PVA composite materials Gahramanli, Lala (Baku State University)
P2-48	Tuning the electric properties of CaTiO ₃ by doping and incorporating GO Xie, Wenjie (TU Darmstadt)
P2-49	High frequency ferromagnetic resonance in hard magnetic iron oxides Vila, Ana (ICMAB-CSIC, Barcelona)
P2-50	Spin-torque ferromagnetic resonance in SrTiO ₃ -based systems Soya, Nozomi (Keio University)
P2-51	Strong field-driven suppression of the thermoelectric conversion in magnetic oxides Ramos, Rafael (Universidade de Santiago de Compostela)